

Nanocrystalline Manganese Substituted Nickel Ferrite Thick Films as PPM Level H₂S Gas Sensors

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Abstract- A simple sol-gel auto combustion technique is introduced for the synthesis of nanocrystalline manganese substituted nickel ferrite dry powders. These dry powders were mechano-chemically mixed with organic binders to prepare thixotropic pastes. Thixotropic pastes of prepared ferrite powders were formulated and screen printed on glass substrates to form thick films, followed by firing at 450°C. The crystal structure, phase, surface morphology and topography of the samples were characterized by X-ray diffraction study, scanning electron microscopy, transmission electron microscopy, etc. The gas sensing behavior of the samples were characterized by exposing the films to various inflammable and toxic gases like LPG, NH₃, CO₂, ethanol, H₂S and Cl₂. It was found that the sensors made from the composition containing x=1.0, exhibits highly selective and most sensitive towards 20 ppm of H₂S gas at 350°C. The effect of operating temperature, gas concentration, type of gases, etc. on gas response were studied and discussed.

Keywords: Sol-gel, Ferrites, H₂S gas sensors, etc.

I. INTRODUCTION

Various polluting, toxic and hazardous gases have been liberated by the industries, which can cause the disastrous and defective deformation of living beings, even at trace levels. This is attributed to explosive industrialization, modernization, globalization, urbanization, and what not? In past decades sensors were based on semiconductor metal oxides like SnO₂, ZnO, WO₃, etc. Spinel oxides (AB₂O₄) have been known for a long time for their interesting optical, electronic and magnetic properties and are thus suitable for various industrial applications, viz. magnetic cores, high-frequency devices, etc. Nowadays, spinel oxides show their characteristic response towards various gases [1-10]. Many researchers synthesized ferrites and worked for the study of their gas sensing properties [11-12].

Also, H₂S is highly toxic and hazardous in such a way that, the few minute exposure to 1000 ppm concentration in air can be fatal to human, high doses can produce unconsciousness and respiratory paralysis. Thus monitoring and control of H₂S gas is today's need. Semiconducting oxides, mixed oxides, spinel oxides, ZnO, CuO/SnO₂ composites, chemically modified CdIn₂O₄ thick films, surface modified Cr₂O₃, WO₃, etc. are studied for H₂S gas sensor [13-19]. However selectivity remains the main challenge for such materials. Hence there always needs for improved H₂S sensor in the industrial area, which has high gas response, high selectivity, low response time and low recovery time along with long term stability. It is known that the electrical resistivity of a semiconducting oxide can be modified by adsorption of gases [20]. This property has been used in semiconductor sensors for the detection of inflammable and toxic gases [21-23]. The semiconductor gas sensors offer good advantages with respect to other gas sensor devices due to their lowest cost, high applicability, high reliability, affordable to laymen, real-time control systems, etc. [24]. In recent years the ferrites have

demonstrated to be good materials for gas sensing applications [25].

The efforts are made to synthesize the nanoscaled ferrite material by sol-gel technique, one of the most suitable, simple, easily available and low cost techniques for the synthesis of Mn substituted Nickel Ferrite.

II. EXPERIMENTAL TECHNIQUES

A. Synthesis of NiFe_{2-x}Mn_xO₄ compositions

High purity AR grade ferric nitrate, manganese nitrate, nickel nitrate and citric acid were used in the synthesis. The metal nitrate solutions were mixed in the required stoichiometric ratios in deionized water. The pH of the solution was adjusted in the range from 9.1 to 9.5 by adding ammonia solution, drop wise and slowly. The solution was allowed for slow heating around 373°K with constant stirring, to obtain floppy mass, which was further subjected to thermal analysis for phase temperature identification. Thus, powdered samples of NiFe_{2-x}Mn_xO₄, (0.0 ≤ x ≤ 2.0) for various concentrations of Fe and Mn were synthesized by sol-gel auto-combustion method. Thick films of prepared samples were fabricated by screen printing technique [26-27].

III. CHARACTERIZATION TECHNIQUES

A. X-Ray Diffraction Studies (XRD)

X-ray diffraction patterns of Mn-substituted nickel ferrites are shown in Fig.1. From Table 1, it is showed that, all the samples of system are cubic and the lattice constant increases with substitution of manganese content. The increase in lattice constant with increase in Mn content is due to the higher ionic radii of Mn³⁺ (0.65Å) ions as compared to Fe³⁺ (0.64Å) ions. Here Mn has strong site preference energy for octahedral site; it tends to occupy the B site rather than A-site. From the X-ray diffraction peaks,

average crystallite size can be estimated using Debye-Scherrer's formula.

$$t = 0.9\lambda / \beta \cos\theta \quad (1)$$

The X-ray density (ρ_x) was calculated using the following relation.

$$\rho_x = 8M/Na^3 \quad (2)$$

Where, N = Avagadros number (6.023×10^{23} atom/mole)

M = Molecular weight in gm

a = Lattice constant

The values of lattice constant (a), crystallite size (t) and X-ray density (ρ_x) are summarized in Table.1. The values of interplanner spacing (d), hkl planes and lattice constant (a) were obtained from XRD data with an accuracy of $\pm 0.03\text{\AA}$.

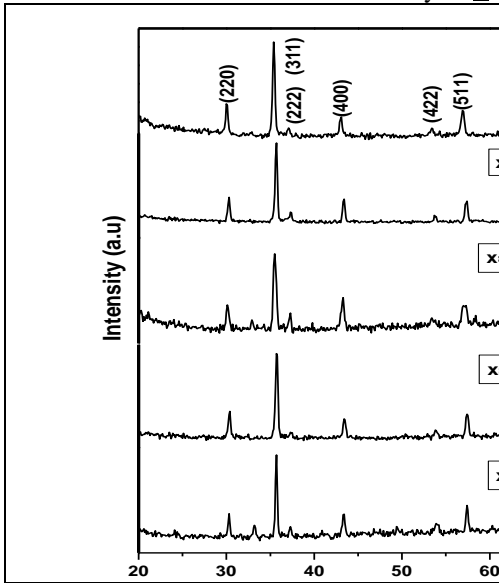


Fig.1: XRD of NiFe_{2-x}Mn_xO₄ system

Dopant Concentration (x)	Lattice Constant 'a' (Å)	X-ray density (gm/cm ³)	Crystallite size (nm)
0.0	8.33	5.37	31
0.5	8.34	5.34	28
1.0	8.35	5.31	24
1.5	8.37	5.26	28
2.0	8.38	5.22	27

Table 1: Lattice constant, crystallite size and X-ray density for all compositions

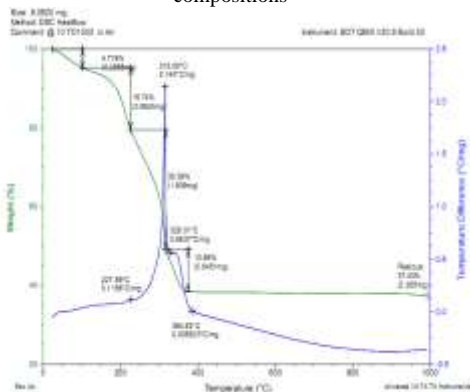
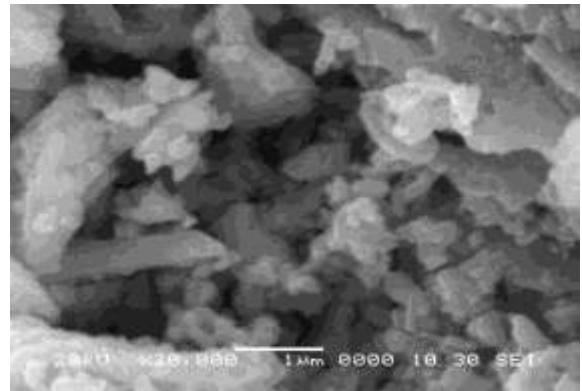


Fig.2: TGA-DTA traces for the sample for x = 1.0

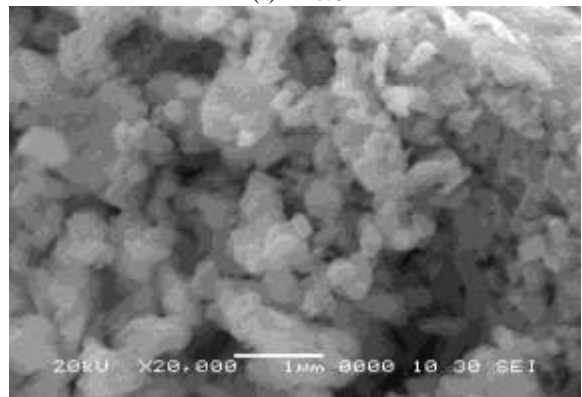
B. Thermal Analysis (TGA and DTA)

Thermogravimetric analysis (TGA) and differential thermal analysis (DTA) of the precursor with $x = 1.0$ was carried out from room temperature to 1000°C to determine its decomposition behavior (Fig. 2). Sample powders of about 6 mg were placed in a platinum crucible, ignited alumina was used as the reference material with the heating rate of 10°C·min⁻¹. The thermal analyses were carried out in static air and some thermoanalytical curves were recorded [27]. TGA of the precursor shows about 50% weight loss during this heating which is due to liberation of CO₂, H₂O, NO_x, etc. It was found that all the decomposition occurs at or below 400°C. Above which, the precursor exhibits a near about constant weight.

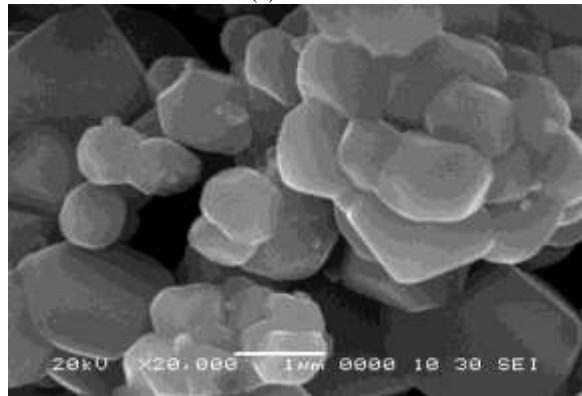
C. Microstructural Studies (SEM and TEM)



(a) x = 0.0



(b) x = 1.0



(c) x = 2.0

Fig. 3 SEM images of NiFe_{2-x}Mn_xO₄ system

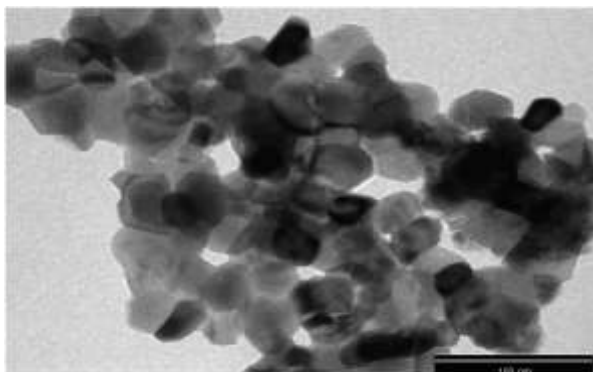


Fig. 4 TEM image of NiFe_{2-x}Mn_xO₄ for x = 1.0

The SEM images of Mn substituted nickel ferrites are shown in Fig.3. It is observed that, the average grain size goes on increasing on substitution of Mn content. They show the presence of very large lumps and found to be agglomeration of small spherical particles. This can be attributed to the generation of large volume of gases during the combustion reaction which occurs in a very short time. The morphology and grain size of manganese substituted nickel ferrite powder (where x=1) was further studied by TEM (Fig. 4). In manganese substituted nickel ferrite, it is noted that all particles are uniform and the average grain size is ~50 nm. Selected area electron diffraction pattern (SAED) of the particles suggests the polycrystallinity of individual crystallite and also confirms the formation of spinel ferrites.

D. Electrical behavior of the sample (Resistivity)

The d.c. electrical resistivity measurements showed linear plots of log (ρ) vs 1000/T°K up to 400°C without any break or inflexion. Silver paste is applied at both the ends of the films for proper contact and connections. The results of electrical measurements show the decrease in resistivity with increasing temperature (Fig. 5) proving the negative temperature coefficient of resistance for the samples to be studied. Increase in temperature of the sample will help the trapped charges to be liberated and participate in the conduction process, with the result of decrease in the resistivity. The electrical resistivity temperature behavior of the NiFe_{2-x}Mn_xO₄ system was found to be obeying Wilson’s law [28].

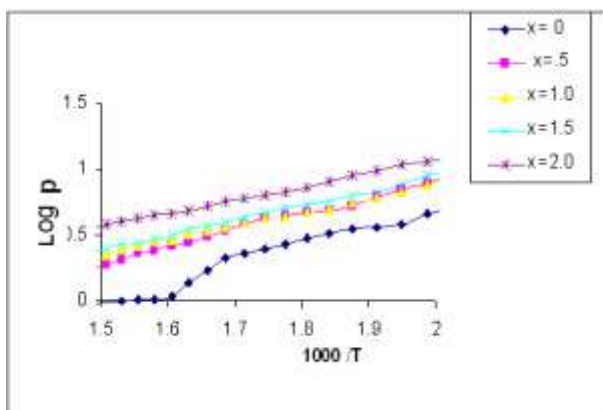


Fig. 5 log ρ versus 1000 / T°K for the sample NiFe_{2-x}Mn_xO₄

IV. GAS SENSING

Sensing parameters for gas sensors viz. gas response, selectivity, response time and recovery time, are defined elsewhere [28-36]. Various parameters affect the gas sensing behavior of the sensor. Their effects are discussed below.

A. Effect of Operating Temperature

Fig. 6 depicts the gas responses of NiFe_{2-x}Mn_xO₄ compositions with different operating temperatures. The NiFe_{2-x}Mn_xO₄ film for x = 1.0 was observed to be a most sensitive film and shows maximum response to 20 ppm H₂S gas at 350°C. The maximum response of this film is attributed to the fact that, it adsorbs more oxygen species on the surface at such a higher temperature (350°C). Upon exposure, the H₂S gas gets oxidized with adsorbed oxygen species on the surface of the film, trapping behind the electrons in the conduction band, which results in increase in conductance of the sensor. Thus this sensor monitors H₂S gas in the open environment.

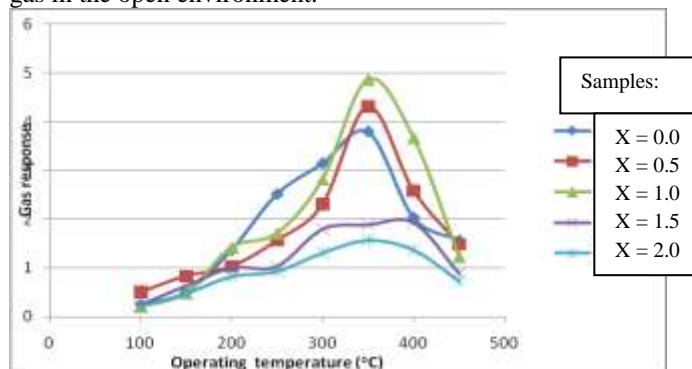


Fig. 6 Variation of gas response with op. temperature

B. Effect of H₂S Gas Concentration

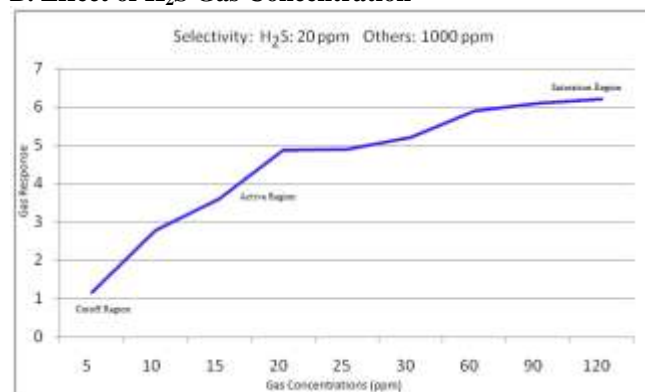


Fig. 7 Variation in gas response with gas concentration (ppm)

Fig. 7 depicts the variation of gas response of sample with H₂S gas concentration at 350°C operating temperature. The sensor was exposed to the varying concentrations of H₂S gas at higher temperature (350°C). The gas response was observed to increase linearly with the gas concentration up to 20 ppm. The increasing rate of gas response was relatively larger upto 20 ppm, and smaller afterwards. The region below 10 ppm, is called as cutoff region. The region in between 10 to 20 ppm is called as active region and above

20 ppm, a saturation region. For the sensors to work proper, the sensor should work in the active region.

C. Selective Nature of the Sensor

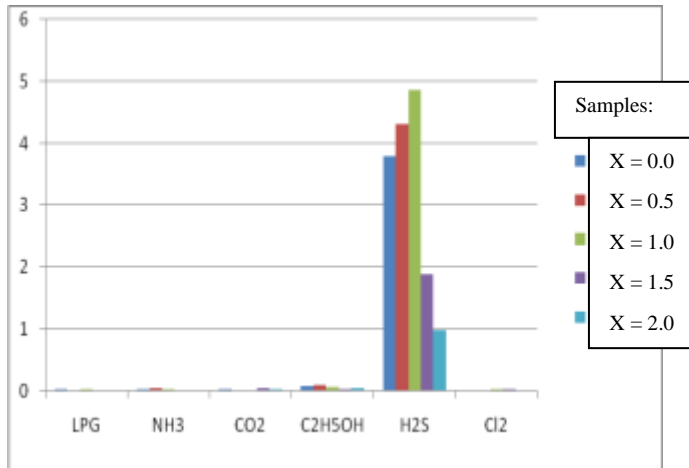


Fig. 8 Selectivity to H₂S gas among various gases

The selective nature of the sensor to H₂S gas at 350°C is depicted in Fig. 8. The sensor showed high selectivity to H₂S against LPG, CO₂, C₂H₅OH, NH₃, and Cl₂ gases even at higher gas concentrations (1000 ppm).

V. DISCUSSION

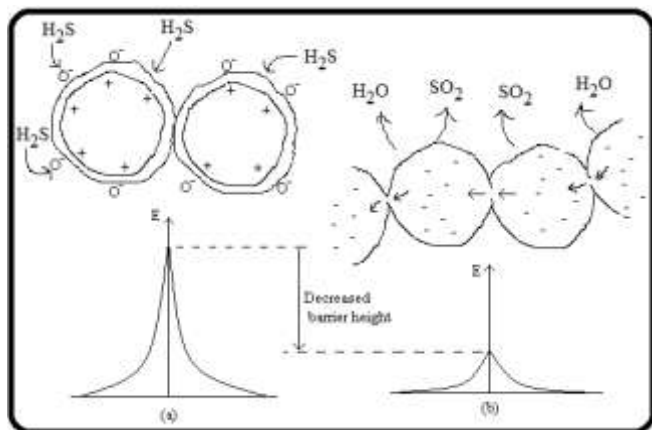
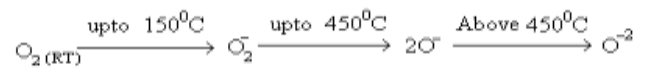


Fig. 9 Actual sensing mechanism to H₂S gas

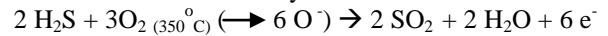
Gas sensing (Fig. 9) is the surface phenomenon. However, the surface is the region where periodicity of the crystal is interrupted, which leads the formation of localized energy levels, in the forbidden gap. Such energy levels can either capture electrons or donate electrons. Such energy levels are completely ionized at higher temperature, causing the increase in conductance of the sensor.

The selective response of this sensor to ppm level H₂S gas at higher temperature could be attributed to the adsorption-desorption type of sensing mechanism. At higher temperature (~350°C), more oxygen species (O⁻) are adsorbed on the surface of the sensor. Upon exposure, the H₂S gas gets oxidized with the adsorbed oxygen species viz. (O₂⁻ → 2O⁻ → O⁻²). The oxygen adsorption on the surface of

the sensor occurs at different temperature ranges [13] are as follows:



During oxidation of the gas, the electrons are released soon and become free to carry the current.



At lower temperature, the smaller amount of oxygen would be adsorbed causes least oxidation of target gas, resulting in smaller gas response. At higher temperature (> 350°C), the target gas may be oxidized before reaching the surface. Therefore, the gas response decreases further with increasing temperature.

This shows n-type conduction mechanism. Thus generated electrons contribute to sudden increase in conductance of the thick film. On exposure to the H₂S containing atmosphere, the resistance was observed to decrease crucially. Thus, obtains good response to 20 ppm H₂S gas. As SO₂ and water vapors are released from the film surface, the sensor recovers back to its original chemical status which would result in fast recovery.

VI. CONCLUSION

Manganese substituted nickel ferrites of nanocrystalline nature were successfully synthesized by sol-gel auto-combustion method. All the synthesized ferrosinzel samples are in nanocrystalline (~50nm) form. Sensor having equivalent amount of Fe and Mn ions (x=1) shows higher response and better selectivity to H₂S gas.

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